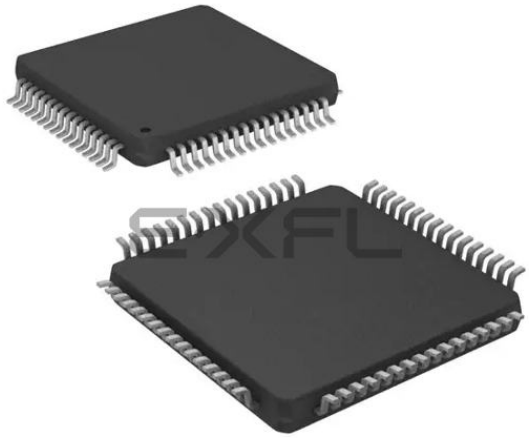
Silicon Labs - EFM32TG11B340F64IQ64-A Datasheet



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"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Discontinued at Digi-Key
Core Processor	ARM® Cortex®-M0+
Core Size	32-Bit Single-Core
Speed	48MHz
Connectivity	CANbus, I²C, IrDA, LINbus, SmartCard, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, DMA, I²S, LCD, POR, PWM, WDT
Number of I/O	53
Program Memory Size	64KB (64K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	32K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 3.8V
Data Converters	A/D 12bit SAR; D/A 12bit
Oscillator Type	Internal
Operating Temperature	-40°C ~ 125°C (TJ)
Mounting Type	Surface Mount
Package / Case	64-TQFP
Supplier Device Package	64-TQFP (10x10)
Purchase URL	https://www.e-xfl.com/product-detail/silicon-labs/efm32tg11b340f64iq64-a

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Frequency limits	f_{HFRCO_BAND}	FREQRANGE = 0, FINETUNINGEN = 0	TBD	—	TBD	MHz
		FREQRANGE = 3, FINETUNINGEN = 0	TBD	—	TBD	MHz
		FREQRANGE = 6, FINETUNINGEN = 0	TBD	—	TBD	MHz
		FREQRANGE = 7, FINETUNINGEN = 0	TBD	—	TBD	MHz
		FREQRANGE = 8, FINETUNINGEN = 0	TBD	—	TBD	MHz
		FREQRANGE = 10, FINETUNINGEN = 0	TBD	—	TBD	MHz
		FREQRANGE = 11, FINETUNINGEN = 0	TBD	—	TBD	MHz
		FREQRANGE = 12, FINETUNINGEN = 0	TBD	—	TBD	MHz
		FREQRANGE = 13, FINETUNINGEN = 0	TBD	—	TBD	MHz

4.1.10 Flash Memory Characteristics[5]

Table 4.17. Flash Memory Characteristics[5]

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Flash erase cycles before failure	EC_{FLASH}		10000	—	—	cycles
Flash data retention	RET_{FLASH}	T ≤ 85 °C	10	—	—	years
		T ≤ 125 °C	10	—	—	years
Word (32-bit) programming time	t_{W_PROG}	Burst write, 128 words, average time per word	20	26	32	µs
		Single word	59	68	83	µs
Page erase time[4]	t_{PERASE}		20	27	35	ms
Mass erase time[1]	t_{MERASE}		20	27	35	ms
Device erase time[2 3]	t_{DERASE}	T ≤ 85 °C	—	54	70	ms
		T ≤ 125 °C	—	54	75	ms
Erase current[6]	I_{ERASE}	Page Erase	—	—	1.7	mA
		Mass or Device Erase	—	—	2.0	mA
Write current[6]	I_{WRITE}		—	—	3.5	mA
Supply voltage during flash erase and write	V_{FLASH}		1.62	—	3.6	V

Note:

1. Mass erase is issued by the CPU and erases all flash.
2. Device erase is issued over the AAP interface and erases all flash, SRAM, the Lock Bit (LB) page, and the User data page Lock Word (ULW).
3. From setting the DEVICEERASE bit in AAP_CMD to 1 until the ERASEBUSY bit in AAP_STATUS is cleared to 0. Internal setup and hold times for flash control signals are included.
4. From setting the ERASEPAGE bit in MSC_WRITECMD to 1 until the BUSY bit in MSC_STATUS is cleared to 0. Internal setup and hold times for flash control signals are included.
5. Flash data retention information is published in the Quarterly Quality and Reliability Report.
6. Measured at 25 °C.

4.1.13 Analog to Digital Converter (ADC)

Specified at 1 Msps, ADCCLK = 16 MHz, BIASPROG = 0, GPBIASACC = 0, unless otherwise indicated.

Table 4.20. Analog to Digital Converter (ADC)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Resolution	$V_{RESOLUTION}$		6	—	12	Bits
Input voltage range[5]	V_{ADCIN}	Single ended	—	—	V_{FS}	V
		Differential	$-V_{FS}/2$	—	$V_{FS}/2$	V
Input range of external reference voltage, single ended and differential	$V_{ADCREFIN\_P}$		1	—	V_{AVDD}	V
Power supply rejection[2]	$PSRR_{ADC}$	At DC	—	80	—	dB
Analog input common mode rejection ratio	$CMRR_{ADC}$	At DC	—	80	—	dB
Current from all supplies, using internal reference buffer. Continous operation. WARMUPMODE[4] = KEEPADCWARM	$I_{ADC\_CONTINOUS\_LP}$	1 Msps / 16 MHz ADCCLK, BIASPROG = 0, GPBIASACC = 1 [3]	—	270	TBD	µA
		250 ksps / 4 MHz ADCCLK, BIASPROG = 6, GPBIASACC = 1 [3]	—	125	—	µA
		62.5 ksps / 1 MHz ADCCLK, BIASPROG = 15, GPBIASACC = 1 [3]	—	80	—	µA
Current from all supplies, using internal reference buffer. Duty-cycled operation. WARMUPMODE[4] = NORMAL	$I_{ADC\_NORMAL\_LP}$	35 ksps / 16 MHz ADCCLK, BIASPROG = 0, GPBIASACC = 1 [3]	—	45	—	µA
		5 ksps / 16 MHz ADCCLK BIASPROG = 0, GPBIASACC = 1 [3]	—	8	—	µA
Current from all supplies, using internal reference buffer. Duty-cycled operation. AWARMUPMODE[4] = KEEPINSTANDBY or KEEPINSLOWACC	$I_{ADC\_STANDBY\_LP}$	125 ksps / 16 MHz ADCCLK, BIASPROG = 0, GPBIASACC = 1 [3]	—	105	—	µA
		35 ksps / 16 MHz ADCCLK, BIASPROG = 0, GPBIASACC = 1 [3]	—	70	—	µA
Current from all supplies, using internal reference buffer. Continous operation. WARMUPMODE[4] = KEEPADCWARM	$I_{ADC\_CONTINOUS\_HP}$	1 Msps / 16 MHz ADCCLK, BIASPROG = 0, GPBIASACC = 0 [3]	—	325	—	µA
		250 ksps / 4 MHz ADCCLK, BIASPROG = 6, GPBIASACC = 0 [3]	—	175	—	µA
		62.5 ksps / 1 MHz ADCCLK, BIASPROG = 15, GPBIASACC = 0 [3]	—	125	—	µA
Current from all supplies, using internal reference buffer. Duty-cycled operation. WARMUPMODE[4] = NORMAL	$I_{ADC\_NORMAL\_HP}$	35 ksps / 16 MHz ADCCLK, BIASPROG = 0, GPBIASACC = 0 [3]	—	85	—	µA
		5 ksps / 16 MHz ADCCLK BIASPROG = 0, GPBIASACC = 0 [3]	—	16	—	µA
Current from all supplies, using internal reference buffer. Duty-cycled operation. AWARMUPMODE[4] = KEEPINSTANDBY or KEEPINSLOWACC	$I_{ADC\_STANDBY\_HP}$	125 ksps / 16 MHz ADCCLK, BIASPROG = 0, GPBIASACC = 0 [3]	—	160	—	µA
		35 ksps / 16 MHz ADCCLK, BIASPROG = 0, GPBIASACC = 0 [3]	—	125	—	µA
Current from HFPERCLK	I_{ADC_CLK}	HFPERCLK = 16 MHz	—	166	—	µA

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Hysteresis (V_{CM} = 1.25 V, BIASPROG[4] = 0x10, FULLBIAS[4] = 1)	$V_{ACMPHYST}$	HYSTSEL[5] = HYST0	TBD	0	TBD	mV
		HYSTSEL[5] = HYST1	TBD	18	TBD	mV
		HYSTSEL[5] = HYST2	TBD	33	TBD	mV
		HYSTSEL[5] = HYST3	TBD	46	TBD	mV
		HYSTSEL[5] = HYST4	TBD	57	TBD	mV
		HYSTSEL[5] = HYST5	TBD	68	TBD	mV
		HYSTSEL[5] = HYST6	TBD	79	TBD	mV
		HYSTSEL[5] = HYST7	TBD	90	TBD	mV
		HYSTSEL[5] = HYST8	TBD	0	TBD	mV
		HYSTSEL[5] = HYST9	TBD	-18	TBD	mV
		HYSTSEL[5] = HYST10	TBD	-33	TBD	mV
		HYSTSEL[5] = HYST11	TBD	-45	TBD	mV
		HYSTSEL[5] = HYST12	TBD	-57	TBD	mV
		HYSTSEL[5] = HYST13	TBD	-67	TBD	mV
		HYSTSEL[5] = HYST14	TBD	-78	TBD	mV
		HYSTSEL[5] = HYST15	TBD	-88	TBD	mV
Comparator delay[3]	$t_{ACMPDELAY}$	BIASPROG[4] = 1, FULLBIAS[4] = 0	—	30	—	µs
		BIASPROG[4] = 0x10, FULLBIAS[4] = 0	—	3.7	—	µs
		BIASPROG[4] = 0x02, FULLBIAS[4] = 1	—	360	—	ns
		BIASPROG[4] = 0x20, FULLBIAS[4] = 1	—	35	—	ns
Offset voltage	$V_{ACMPOFFSET}$	BIASPROG[4] =0x10, FULLBIAS[4] = 1	TBD	—	TBD	mV
Reference voltage	$V_{ACMPREF}$	Internal 1.25 V reference	TBD	1.25	TBD	V
		Internal 2.5 V reference	TBD	2.5	TBD	V
Capacitive sense internal resistance	R_{CSRES}	CSRESSEL[6] = 0	—	infinite	—	kΩ
		CSRESSEL[6] = 1	—	15	—	kΩ
		CSRESSEL[6] = 2	—	27	—	kΩ
		CSRESSEL[6] = 3	—	39	—	kΩ
		CSRESSEL[6] = 4	—	51	—	kΩ
		CSRESSEL[6] = 5	—	100	—	kΩ
		CSRESSEL[6] = 6	—	162	—	kΩ
		CSRESSEL[6] = 7	—	235	—	kΩ

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit

Note:

1. ACMPVDD is a supply chosen by the setting in ACMPn_CTRL_PWRSEL and may be IOVDD, AVDD or DVDD.
2. The total ACMP current is the sum of the contributions from the ACMP and its internal voltage reference. $I_{ACMPTOTAL} = I_{ACMP} + I_{ACMPREF}$.
3. ± 100 mV differential drive.
4. In ACMPn_CTRL register.
5. In ACMPn_HYSTERESIS registers.
6. In ACMPn_INPUTSEL register.

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit

Note:

1. Supply current specifications are for VDAC circuitry operating with static output only and do not include current required to drive the load.
2. In differential mode, the output is defined as the difference between two single-ended outputs. Absolute voltage on each output is limited to the single-ended range.
3. Entire range is monotonic and has no missing codes.
4. Current from HFPERCLK is dependent on HFPERCLK frequency. This current contributes to the total supply current used when the clock to the DAC module is enabled in the CMU.
5. Gain is calculated by measuring the slope from 10% to 90% of full scale. Offset is calculated by comparing actual VDAC output at 10% of full scale to ideal VDAC output at 10% of full scale with the measured gain.
6. PSRR calculated as 20 * $\log_{10}(\Delta VDD / \Delta V_{OUT})$, VDAC output at 90% of full scale

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit

Note:

1. Specified configuration for 3X-Gain configuration is: INCBW = 1, HCMDIS = 1, RESINSEL = VSS, V_{INPUT} = 0.5 V, V_{OUTPUT} = 1.5 V. Nominal voltage gain is 3.
2. If the maximum C_{LOAD} is exceeded, an isolation resistor is required for stability. See AN0038 for more information.
3. When INCBW is set to 1 the OPAMP bandwidth is increased. This is allowed only when the non-inverting close-loop gain is ≥ 3, or the OPAMP may not be stable.
4. Current into the load resistor is excluded. When the OPAMP is connected with closed-loop gain > 1, there will be extra current to drive the resistor feedback network. The internal resistor feedback network has total resistance of 143.5 kOhm, which will cause another ~10 µA current when the OPAMP drives 1.5 V between output and ground.
5. Step between 0.2V and V_{OPA}-0.2V, 10%-90% rising/falling range.
6. From enable to output settled. In sample-and-off mode, RC network after OPAMP will contribute extra delay. Settling error < 1mV.
7. In unit gain connection, UGF is the gain-bandwidth product of the OPAMP. In 3x Gain connection, UGF is the gain-bandwidth product of the OPAMP and 1/3 attenuation of the feedback network.
8. Specified configuration for Unit gain buffer configuration is: INCBW = 0, HCMDIS = 0, RESINSEL = DISABLE. V_{INPUT} = 0.5 V, V_{OUTPUT} = 0.5 V.
9. When HCMDIS=1 and input common mode transitions the region from V_{OPA}-1.4V to V_{OPA}-1V, input offset will change. PSRR and CMRR specifications do not apply to this transition region.

4.1.18 LCD Driver

Table 4.25. LCD Driver

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Frame rate	f_{LCDFR}		TBD	—	TBD	Hz
LCD supply range[2]	V_{LCDIN}		1.8	—	3.8	V
LCD output voltage range	V_{LCD}	Current source mode, No external LCD capacitor	2.0	—	V_{LCDIN}-0.4	V
		Step-down mode with external LCD capacitor	2.0	—	V_{LCDIN}	V
		Charge pump mode with external LCD capacitor	2.0	—	Min of 3.8 and 1.9 * V_{LCDIN}	V
Contrast control step size	$STEP_{CONTRAST}$	Current source mode	—	64	—	mV
		Charge pump or Step-down mode	—	43	—	mV
Contrast control step accuracy[1]	$ACC_{CONTRAST}$		—	+/-4	—	%

Note:

1. Step size accuracy is measured relative to the typical step size, and typ value represents one standard deviation.
2. V_{LCDIN} is selectable between the AVDD or DVDD supply pins, depending on EMU_PWRCTRL_ANASW.

4.1.21.2 I2C Fast-mode (Fm)[1]

Table 4.29. I2C Fast-mode (Fm)[1]

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
SCL clock frequency[2]	f_{SCL}		0	—	400	kHz
SCL clock low time	t_{LOW}		1.3	—	—	µs
SCL clock high time	t_{HIGH}		0.6	—	—	µs
SDA set-up time	t_{SU_DAT}		100	—	—	ns
SDA hold time[3]	t_{HD_DAT}		100	—	900	ns
Repeated START condition set-up time	t_{SU_STA}		0.6	—	—	µs
(Repeated) START condition hold time	t_{HD_STA}		0.6	—	—	µs
STOP condition set-up time	t_{SU_STO}		0.6	—	—	µs
Bus free time between a STOP and START condition	t_{BUF}		1.3	—	—	µs

Note:

1. For CLHR set to 1 in the I2Cn_CTRL register.
2. For the minimum HFPERCLK frequency required in Fast-mode, refer to the I2C chapter in the reference manual.
3. The maximum SDA hold time ($t_{HD,DAT}$) needs to be met only when the device does not stretch the low time of SCL (t_{LOW}).

4.1.21.3 I2C Fast-mode Plus (Fm+)[1]

Table 4.30. I2C Fast-mode Plus (Fm+)[1]

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
SCL clock frequency[2]	f_{SCL}		0	—	1000	kHz
SCL clock low time	t_{LOW}		0.5	—	—	µs
SCL clock high time	t_{HIGH}		0.26	—	—	µs
SDA set-up time	t_{SU_DAT}		50	—	—	ns
SDA hold time	t_{HD_DAT}		100	—	—	ns
Repeated START condition set-up time	t_{SU_STA}		0.26	—	—	µs
(Repeated) START condition hold time	t_{HD_STA}		0.26	—	—	µs
STOP condition set-up time	t_{SU_STO}		0.26	—	—	µs
Bus free time between a STOP and START condition	t_{BUF}		0.5	—	—	µs

Note:
1. For CLHR set to 0 or 1 in the I2Cn_CTRL register.
2. For the minimum HFPERCLK frequency required in Fast-mode Plus, refer to the I2C chapter in the reference manual.

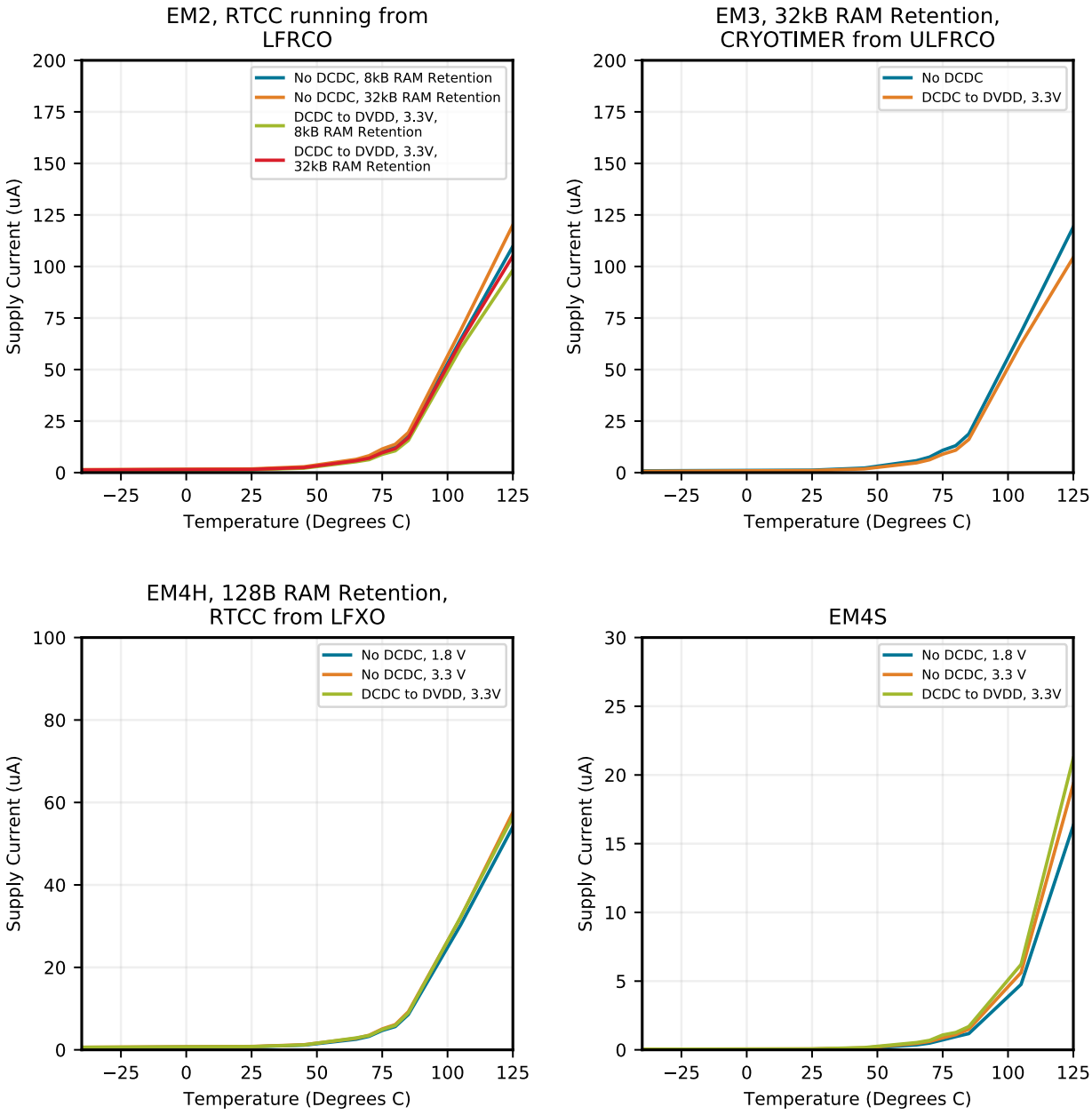

Figure 4.5. EM2, EM3, EM4H and EM4S Typical Supply Current vs. Temperature

5.3 EFM32TG11B5xx in QFP64 Device Pinout

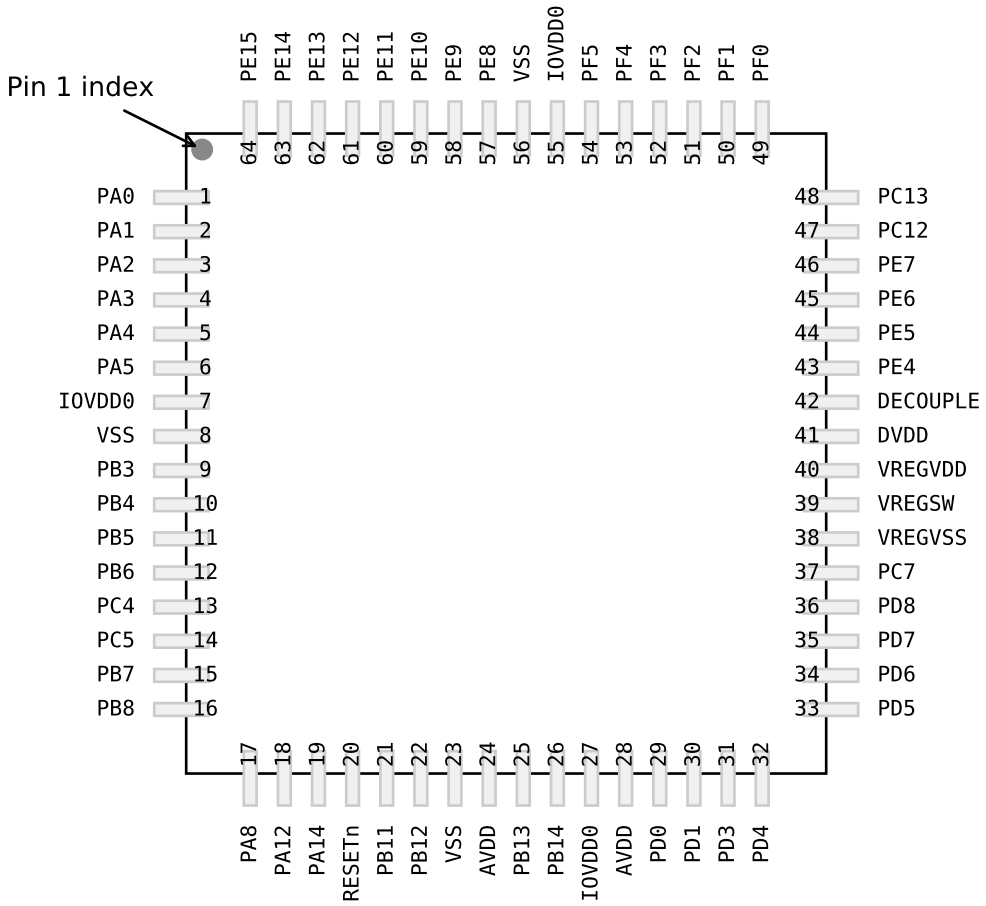

Figure 5.3. EFM32TG11B5xx in QFP64 Device Pinout

The following table provides package pin connections and general descriptions of pin functionality. For detailed information on the supported features for each GPIO pin, see 5.14 GPIO Functionality Table or 5.15 Alternate Functionality Overview.

Table 5.3. EFM32TG11B5xx in QFP64 Device Pinout

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PA0	1	GPIO	PA1	2	GPIO
PA2	3	GPIO	PA3	4	GPIO
PA4	5	GPIO	PA5	6	GPIO
IOVDD0	7 27 55	Digital IO power supply 0.	VSS	8 23 56	Ground
PB3	9	GPIO	PB4	10	GPIO
PB5	11	GPIO	PB6	12	GPIO

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PC4	13	GPIO	PC5	14	GPIO
PB7	15	GPIO	PB8	16	GPIO
PA8	17	GPIO	PA9	18	GPIO
PA10	19	GPIO	RESETn	20	Reset input, active low. To apply an external reset source to this pin, it is required to only drive this pin low during reset, and let the internal pull-up ensure that reset is released.
PB11	21	GPIO	AVDD	23 27	Analog power supply.
PB13	24	GPIO	PB14	25	GPIO
PD0	28	GPIO (5V)	PD1	29	GPIO
PD2	30	GPIO (5V)	PD3	31	GPIO
PD4	32	GPIO	PD5	33	GPIO
PD6	34	GPIO	PD7	35	GPIO
PD8	36	GPIO	PC6	37	GPIO
PC7	38	GPIO	DVDD	39	Digital power supply.
DECOUPLE	40	Decouple output for on-chip voltage regulator. An external decoupling capacitor is required at this pin.	PC8	41	GPIO
PC9	42	GPIO	PC10	43	GPIO (5V)
PC11	44	GPIO (5V)	PC12	45	GPIO (5V)
PC13	46	GPIO (5V)	PC14	47	GPIO (5V)
PC15	48	GPIO (5V)	PF0	49	GPIO (5V)
PF1	50	GPIO (5V)	PF2	51	GPIO
PF3	52	GPIO	PF4	53	GPIO
PF5	54	GPIO	PE8	57	GPIO
PE9	58	GPIO	PE10	59	GPIO
PE11	60	GPIO	PE12	61	GPIO
PE13	62	GPIO	PE14	63	GPIO
PE15	64	GPIO			

Note:
1. GPIO with 5V tolerance are indicated by (5V).

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PB4	10	GPIO	PB5	11	GPIO
PB6	12	GPIO	PC4	13	GPIO
PC5	14	GPIO	PB7	15	GPIO
PB8	16	GPIO	PA8	17	GPIO
PA12	18	GPIO	PA13	19	GPIO (5V)
PA14	20	GPIO	RESETn	21	Reset input, active low. To apply an external reset source to this pin, it is required to only drive this pin low during reset, and let the internal pull-up ensure that reset is released.
PB11	22	GPIO	PB12	23	GPIO
AVDD	24 28	Analog power supply.	PB13	25	GPIO
PB14	26	GPIO	PD0	29	GPIO (5V)
PD1	30	GPIO	PD3	31	GPIO
PD4	32	GPIO	PD5	33	GPIO
PD6	34	GPIO	PD7	35	GPIO
PD8	36	GPIO	PC7	37	GPIO
VREGSW	39	DCDC regulator switching node	VREGVDD	40	Voltage regulator VDD input
DVDD	41	Digital power supply.	DECOUPLE	42	Decouple output for on-chip voltage regulator. An external decoupling capacitor is required at this pin.
PE4	43	GPIO	PE5	44	GPIO
PE6	45	GPIO	PE7	46	GPIO
PC12	47	GPIO (5V)	PC13	48	GPIO (5V)
PF0	49	GPIO (5V)	PF1	50	GPIO (5V)
PF2	51	GPIO	PF3	52	GPIO
PF4	53	GPIO	PF5	54	GPIO
PE8	56	GPIO	PE9	57	GPIO
PE10	58	GPIO	PE11	59	GPIO
PE12	60	GPIO	PE13	61	GPIO
PE14	62	GPIO	PE15	63	GPIO
PA15	64	GPIO			

Note:

1. GPIO with 5V tolerance are indicated by (5V).

GPIO Name	Pin Alternate Functionality / Description			
	Analog	Timers	Communication	Other
PC15	VDAC0_OUT1ALT / OPA1_OUTALT #3 BU-SACMP1Y BUSACMP1X	TIM0_CDTI2 #1 TIM1_CC2 #0 WTIM0_CC0 #4 LE-TIM0_OUT1 #5	US0_CLK #3 US1_CLK #3 US3_RTS #3 U0_RX #3 LEU0_RX #5	LES_CH15 PRS_CH1 #2
PF0	BUSDY BUSCX	TIM0_CC0 #4 WTIM0_CC1 #4 LE-TIM0_OUT0 #2	CAN0_RX #1 US1_CLK #2 US2_TX #5 LEU0_TX #3 I2C0_SDA #5	DBG_SWCLKTCK BOOT_TX
PF1	BUSCY BUSDX	TIM0_CC1 #4 WTIM0_CC2 #4 LE-TIM0_OUT1 #2	US1_CS #2 US2_RX #5 U0_TX #5 LEU0_RX #3 I2C0_SCL #5	PRS_CH4 #2 DBG_SWDIOTMS GPIO_EM4WU3 BOOT_RX
PF2	BUSDY BUSCX LCD_SEG0	TIM0_CC2 #4 TIM1_CC0 #5	CAN0_TX #1 US1_TX #5 US2_CLK #5 U0_RX #5 LEU0_TX #4 I2C1_SCL #4	CMU_CLK0 #4 PRS_CH0 #3 ACMP1_O #0 DBG_TDO GPIO_EM4WU4
PF3	BUSCY BUSDX LCD_SEG1	TIM0_CDTI0 #2 TIM1_CC1 #5	US1_CTS #2	CMU_CLK1 #4 PRS_CH0 #1
PF4	BUSDY BUSCX LCD_SEG2	TIM0_CDTI1 #2 TIM1_CC2 #5	US1_RTS #2	PRS_CH1 #1
PF5	BUSCY BUSDX LCD_SEG3	TIM0_CDTI2 #2 TIM1_CC3 #6	US2_CS #5	PRS_CH2 #1 DBG_TDI
PE8	BUSDY BUSCX LCD_SEG4			PRS_CH3 #1
PE9	BUSCY BUSDX LCD_SEG5			
PE10	BUSDY BUSCX LCD_SEG6	TIM1_CC0 #1 WTIM0_CDTI0 #0	US0_TX #0	PRS_CH2 #2 GPIO_EM4WU9
PE11	BUSCY BUSDX LCD_SEG7	TIM1_CC1 #1 WTIM0_CDTI1 #0	US0_RX #0	LES_ALTEX5 PRS_CH3 #2
PE12	BUSDY BUSCX LCD_SEG8	TIM1_CC2 #1 WTIM0_CDTI2 #0 LE-TIM0_OUT0 #4	US0_RX #3 US0_CLK #0 I2C0_SDA #6	CMU_CLK1 #2 CMU_CLKI0 #6 LES_AL-TEX6 PRS_CH1 #3
PE13	BUSCY BUSDX LCD_SEG9	TIM1_CC3 #1 LE-TIM0_OUT1 #4	US0_TX #3 US0_CS #0 I2C0_SCL #6	LES_ALTEX7 PRS_CH2 #3 ACMP0_O #0 GPIO_EM4WU5
PE14	BUSDY BUSCX LCD_SEG10		US0_CTS #0 LEU0_TX #2	
PE15	BUSCY BUSDX LCD_SEG11		US0_RTS #0 LEU0_RX #2	
PA15	BUSAY BUSBX LCD_SEG12		US2_CLK #3	

Alternate	LOCATION		
Functionality	0 - 3	4 - 7	Description
TIM0_CC0	0: PA0 2: PD1 3: PB6	4: PF0 5: PC4 6: PA8 7: PA1	Timer 0 Capture Compare input / output channel 0.
TIM0_CC1	0: PA1 2: PD2 3: PC0	4: PF1 5: PC5 6: PA9 7: PA0	Timer 0 Capture Compare input / output channel 1.
TIM0_CC2	0: PA2 2: PD3 3: PC1	4: PF2 6: PA10 7: PA13	Timer 0 Capture Compare input / output channel 2.
TIM0_CDTI0	0: PA3 1: PC13 2: PF3 3: PC2	4: PB7	Timer 0 Complimentary Dead Time Insertion channel 0.
TIM0_CDTI1	0: PA4 1: PC14 2: PF4 3: PC3	4: PB8	Timer 0 Complimentary Dead Time Insertion channel 1.
TIM0_CDTI2	0: PA5 1: PC15 2: PF5 3: PC4	4: PB11	Timer 0 Complimentary Dead Time Insertion channel 2.
TIM1_CC0	0: PC13 1: PE10 3: PB7	4: PD6 5: PF2	Timer 1 Capture Compare input / output channel 0.
TIM1_CC1	0: PC14 1: PE11 3: PB8	4: PD7 5: PF3	Timer 1 Capture Compare input / output channel 1.
TIM1_CC2	0: PC15 1: PE12 3: PB11	4: PC13 5: PF4	Timer 1 Capture Compare input / output channel 2.
TIM1_CC3	0: PC12 1: PE13 2: PB3 3: PB12	4: PC14 6: PF5	Timer 1 Capture Compare input / output channel 3.
U0_CTS	 2: PA5 3: PC13	4: PB7 5: PD5	UART0 Clear To Send hardware flow control input.
U0_RTS	 2: PA6 3: PC12	4: PB8 5: PD6	UART0 Request To Send hardware flow control output.
U0_RX	 2: PA4 3: PC15	4: PC5 5: PF2 6: PE4	UART0 Receive input.

Alternate	LOCATION		
Functionality	0 - 3	4 - 7	Description
VDAC0_OUT0 / OPA0_OUT	0: PB11		Digital to Analog Converter DAC0 output channel number 0.
VDAC0_OUT0ALT / OPA0_OUTALT	0: PC0 1: PC1 2: PC2 3: PC3	4: PD0	Digital to Analog Converter DAC0 alternative output for channel 0.
VDAC0_OUT1 / OPA1_OUT	0: PB12		Digital to Analog Converter DAC0 output channel number 1.
VDAC0_OUT1ALT / OPA1_OUTALT	0: PC12 1: PC13 2: PC14 3: PC15	4: PD1	Digital to Analog Converter DAC0 alternative output for channel 1.
WTIM0_CC0	0: PE4 1: PA6	4: PC15 6: PB3 7: PC1	Wide timer 0 Capture Compare input / output channel 0.
WTIM0_CC1	0: PE5	4: PF0 6: PB4 7: PC2	Wide timer 0 Capture Compare input / output channel 1.
WTIM0_CC2	0: PE6	4: PF1 6: PB5 7: PC3	Wide timer 0 Capture Compare input / output channel 2.
WTIM0_CDTI0	0: PE10 2: PA12	4: PD4	Wide timer 0 Complimentary Dead Time Insertion channel 0.
WTIM0_CDTI1	0: PE11 2: PA13	4: PD5	Wide timer 0 Complimentary Dead Time Insertion channel 1.
WTIM0_CDTI2	0: PE12 2: PA14	4: PD6	Wide timer 0 Complimentary Dead Time Insertion channel 2.
WTIM1_CC0	0: PB13 1: PD2 2: PD6 3: PC7	5: PE7	Wide timer 1 Capture Compare input / output channel 0.
WTIM1_CC1	0: PB14 1: PD3 2: PD7	4: PE4	Wide timer 1 Capture Compare input / output channel 1.
WTIM1_CC2	0: PD0 1: PD4 2: PD8	4: PE5	Wide timer 1 Capture Compare input / output channel 2.

Table 5.20. VDAC0 / OPA Bus and Pin Mapping

Port	Bus	CH31	CH30	CH29	CH28	CH27	CH26	CH25	CH24	CH23	CH22	CH21	CH20	CH19	CH18	CH17	CH16	CH15	CH14	CH13	CH12	CH11	CH10	CH9	CH8	CH7	CH6	CH5	CH4	CH3	CH2	CH1	CH0
OPA0_N																																	
APORT1Y	BUSAY			PB13		PB11						PB5		PB3				PA15		PA13				PA9				PA5		PA3		PA1	
APORT2Y	BUSBY		PB14		PB12						PB6		PB4						PA14				PA10				PA6		PA4		PA2		PA0
APORT3Y	BUSCY											PF5		PF3		PF1		PE15		PE13		PE11		PE9		PE7		PE5					
APORT4Y	BUSDY												PF4		PF2		PF0		PE14		PE12		PE10		PE8		PE6		PE4				
OPA0_P																																	
APORT1X	BUSAX		PB14		PB12						PB6		PB4					PA15	PA14				PA10				PA6		PA4		PA2		PA0
APORT2X	BUSBX			PB13		PB11						PB5		PB3				PA15		PA13				PA9				PA5		PA3		PA1	
APORT3X	BUSCX												PF4		PF2		PF0		PE14		PE12		PE10		PE8		PE6		PE4				
APORT4X	BUSDX											PF5		PF3		PF1		PE15		PE13		PE11		PE9		PE7		PE5					

7.3 QFN80 Package Marking

Figure 7.3. QFN80 Package Marking

The package marking consists of:

- PPPPPPPPPP – The part number designation.
- TTTTTT – A trace or manufacturing code. The first letter is the device revision.
- YY – The last 2 digits of the assembly year.
- WW – The 2-digit workweek when the device was assembled.

Table 8.2. TQFP64 PCB Land Pattern Dimensions

Dimension	Min	Max
C1	11.30	11.40
C2	11.30	11.40
E	0.50 BSC	
X	0.20	0.30
Y	1.40	1.50

Note:

1. All dimensions shown are in millimeters (mm) unless otherwise noted.
2. This Land Pattern Design is based on the IPC-7351 guidelines.
3. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 µm minimum, all the way around the pad.
4. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
5. The stencil thickness should be 0.125 mm (5 mils).
6. The ratio of stencil aperture to land pad size can be 1:1 for all pads.
7. A No-Clean, Type-3 solder paste is recommended.
8. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

8.3 TQFP64 Package Marking

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The package marking consists of:

- PPPPPPPPPP – The part number designation.
- TTTTTT – A trace or manufacturing code. The first letter is the device revision.
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